

## **Legacy Device: Motorola MC1350**

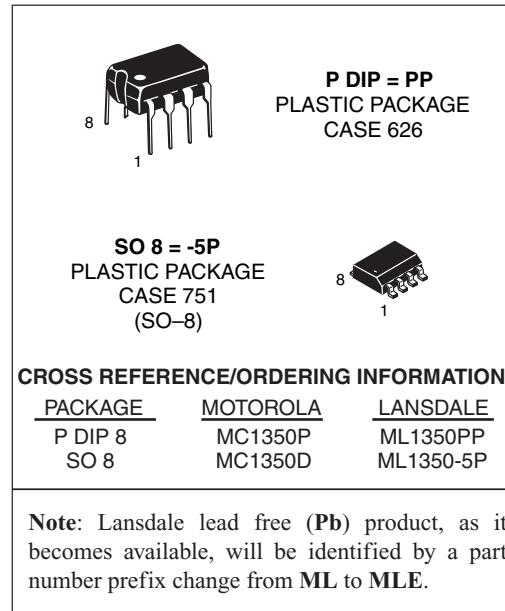
The ML1350 is an integrated circuit featuring wide range AGC for use as a linear IF amplifier in AM radio, shortwave, TV and instrumentation.

- Power Gain: 50 dB Typ at 45 MHz  
50 dB Typ at 58 MHz
  - AGC Range: 60 dB Min, DC to 45 MHz
  - Nearly Constant Input & Output Admittance over the Entire AGC Range
  - Y21 Constant (-3.0 dB) to 90 MHz
  - Low Reverse Transfer Admittance: << 1.0  $\mu\text{mho}$  Typical
  - 12 V Operation, Single-Polarity Power Supply
  - Operating Temperature Range  $T_A = 0^\circ$  to  $+75^\circ$  C

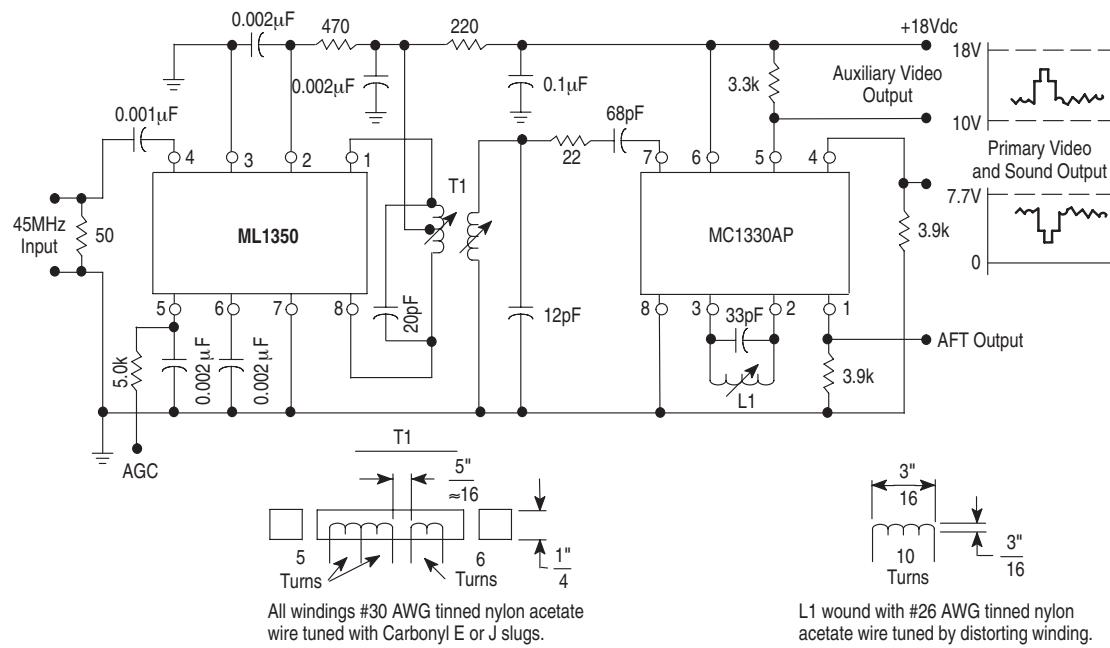
Note: See ML1490 Similar Function

**MAXIMUM RATINGS** ( $T_A = +25^\circ\text{C}$ , unless otherwise noted.)

Rating	Symbol	Value	Unit
Power Supply Voltage	V <sup>+</sup>	+18	Vdc
Output Supply Voltage	V <sub>1</sub> , V <sub>8</sub>	+18	Vdc
AGC Supply Voltage	V <sub>AGC</sub>	V <sup>+</sup>	Vdc
Differential Input Voltage	V <sub>in</sub>	5.0	Vdc
Power Dissipation (Package Limitation) Plastic Package Derate above 25°C	P <sub>D</sub>	625 5.0	mW mW/°C
Operating Temperature Range	T <sub>A</sub>	0 to +75	°C



**Figure 1.** Typical ML1350 Video IF Amplifier and MC1330 Low-Level Video Detector Circuit



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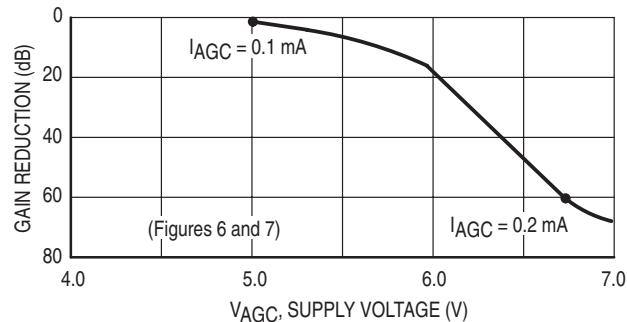
**ELECTRICAL CHARACTERISTICS** ( $V^+ = +12$  Vdc,  $T_A = +25^\circ\text{C}$ , unless otherwise noted.)

Characteristics	Symbol	Min	Typ	Max	Unit
AGC Range, 45 MHz (5.0 V to 7.0 V) (Figure 1)		60	68	—	dB
Power Gain (Pin 5 grounded via a 5.1 kΩ resistor) $f = 58$ MHz, BW = 4.5 MHz $f = 45$ MHz, BW = 4.5 MHz $f = 10.7$ MHz, BW = 350 kHz $f = 455$ kHz, BW = 20 kHz	$A_p$	— 46 — —	48 50 58 62	— — — —	dB
Maximum Differential Voltage Swing 0 dB AGC −30 dB AGC	$V_O$	— —	20 8.0	— —	$V_{pp}$
Output Stage Current (Pins 1 and 8)	$I_1 + I_8$	—	5.6	—	mA
Total Supply Current (Pins 1, 2 and 8)	$I_S$	—	14	17	mAdc
Power Dissipation	$P_D$	—	168	204	mW

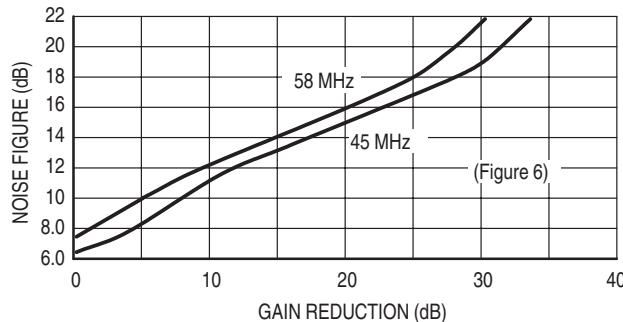
**DESIGN PARAMETERS**, Typical Values ( $V^+ = +12$  Vdc,  $T_A = +25^\circ\text{C}$ , unless otherwise noted.)

Parameter	Symbol	Frequency				Unit
		455 kHz	10.7 MHz	45 MHz	58 MHz	
Single-Ended Input Admittance	$g_{11}$ $b_{11}$	0.31 0.022	0.36 0.50	0.39 2.30	0.5 2.75	mmho
Input Admittance Variations with AGC (0 dB to 60 dB)	$\Delta g_{11}$ $\Delta b_{11}$	— —	— —	60 0	— —	μmho
Differential Output Admittance	$g_{22}$ $b_{22}$	4.0 3.0	4.4 110	30 390	60 510	μmho
Output Admittance Variations with AGC (0 dB to 60 dB)	$\Delta g_{22}$ $\Delta b_{22}$	— —	— —	4.0 90	— —	μmho
Reverse Transfer Admittance (Magnitude)	$ y_{12} $	<< 1.0	<< 1.0	<< 1.0	<< 1.0	μmho
Forward Transfer Admittance Magnitude Angle (0 dB AGC) Angle (−30 dB AGC)	$ y_{21} $ $<y_{21}$ $<y_{21}$	160 −5.0 −3.0	160 −20 −18	200 −80 −69	180 −105 −90	mmho Degrees Degrees
Single-Ended Input Capacitance	$C_{in}$	7.2	7.2	7.4	7.6	pF
Differential Output Capacitance	$C_O$	1.2	1.2	1.3	1.6	pF

**Figure 2. Typical Gain Reduction**



**Figure 3. Noise Figure versus Gain Reduction**

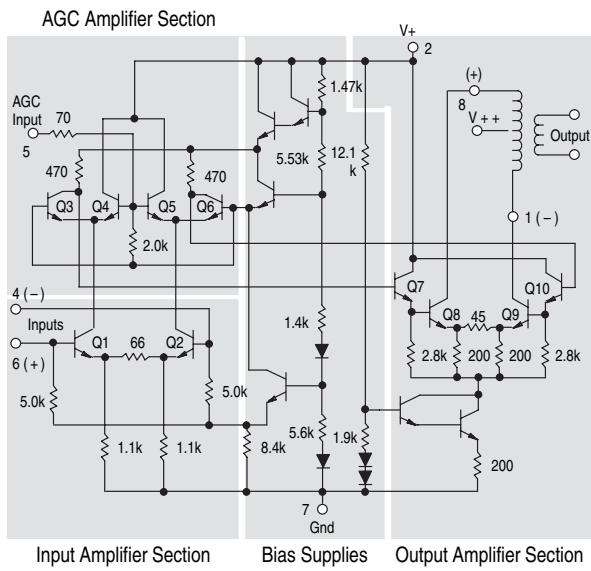


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## GENERAL OPERATING INFORMATION

The input amplifiers (Q1 and Q2) operate at constant emitter currents so that input impedance remains independent of AGC action. Input signals may be applied single-ended or differentially (for AC) with identical results. Terminals 4 and 6 may be driven from a transformer, but a DC path from either terminal to ground is not permitted.

Figure 4. Circuit Schematic



AGC action occurs as a result of an increasing voltage on the base of Q4 and Q5 causing these transistors to conduct more heavily thereby shunting signal current from the interstage amplifiers Q3 and Q6. The output amplifiers are supplied from an active current source to maintain constant quiescent bias thereby holding output admittance nearly constant. Collector voltage for the output amplifier must be supplied through a center-tapped tuning coil to Pins 1 and 8. The 12 V supply ( $V_+$ ) at Pin 2 may be used for this purpose, but output admittance remains more nearly constant if a separate 15 V supply ( $V_{++}$ ) is used, because the base voltage on the output amplifier varies with AGC bias.

Figure 5. Frequency Response Curve  
(45 MHz and 58 MHz)

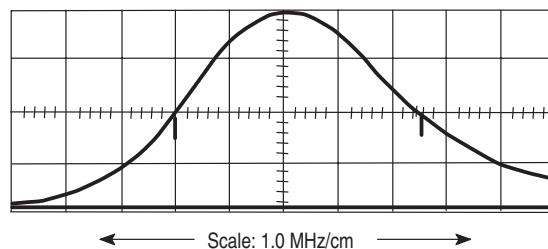
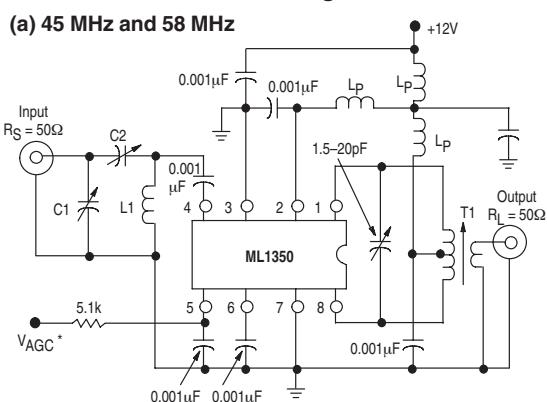


Figure 6. Power Gain, AGC and Noise Figure Test Circuits



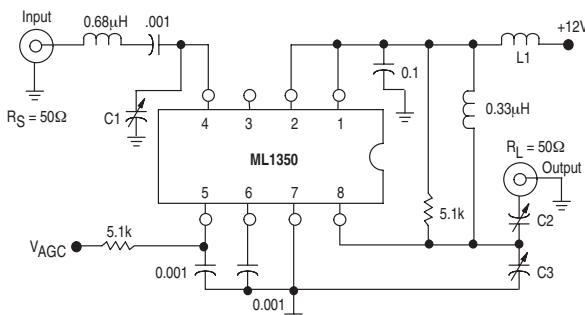
\*Connect to ground for maximum power gain test.

All power supply chokes ( $L_p$ ), are self-resonant at input frequency.  $L_p \geq 20 \text{ k}\Omega$ . See Figure 5 for Frequency Response Curve.

L1 @ 45 MHz = 7 1/4 Turns on a 1/4" coil form  
@ 58 MHz = 6 Turns on a 1/4" coil form

T1 Primary Winding = 18 Turns on a 1/4" coil form, center-tapped, #25 AWG  
Secondary Winding = 2 Turns centered over Primary Winding @ 45 MHz  
= 1 Turn @ 58 MHz  
Slug = Carbonyl E or J

(b) Alternate 45 MHz



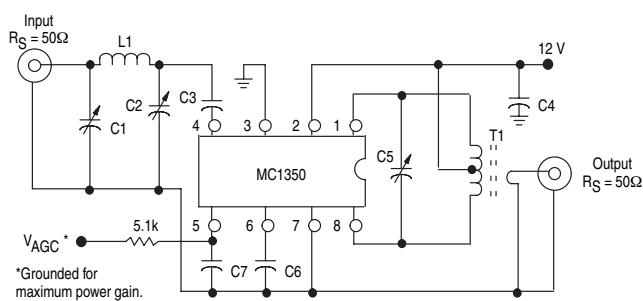
L1	Ferrite Core 14 Turns 28 S.W.G.
C1	5-25 pF
C2	5-25 pF
C3	5-25 pF

	45 MHz		58 MHz	
L1	0.4 μH	$Q \geq 100$	0.3 μH	$Q \geq 100$
T1	1.3 μH to 3.4 μH	$Q \geq 100 @ 2.0 \mu\text{H}$	1.2 μH to 3.8 μH	$Q \geq 100 @ 2.0 \mu\text{H}$
C1	50 pF to 160 pF		8.0 pF to 60 pF	
C2	8.0 pF to 60 pF		3.0 pF to 35 pF	

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Legacy Applications Information

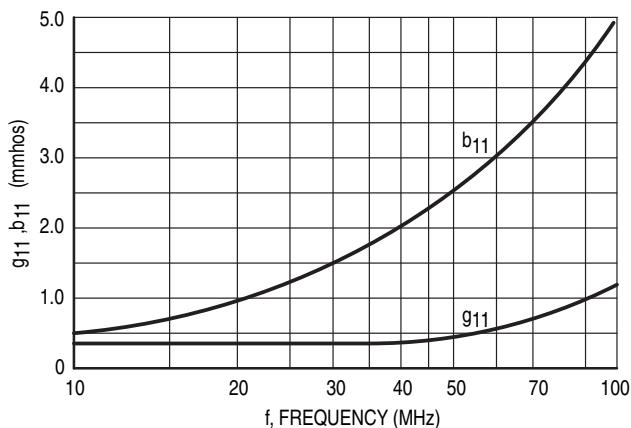
**Figure 7. Power Gain and AGC Test Circuit  
(455 kHz and 10.7 MHz)**



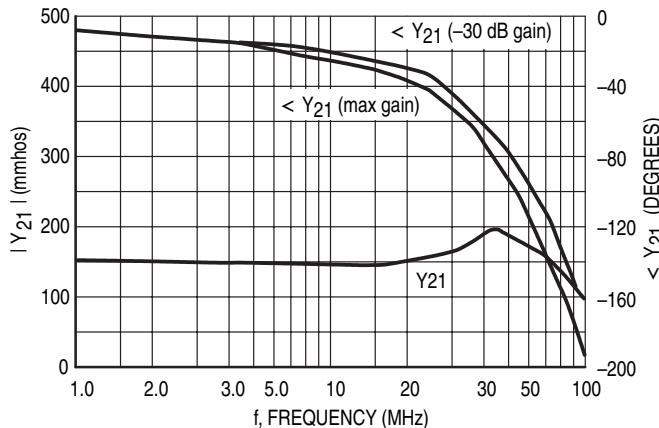
Component	Frequency	
	455 kHz	10.7 MHz
C1	—	80–450 pF
C2	—	5.0–80 pF
C3	0.05 μF	0.001 μF
C4	0.05 μF	0.05 μF
C5	0.001 μF	36 pF
C8	0.05 μF	0.05 μF
C7	0.05 μF	0.05 μF
L1	—	4.6 μF
T1	Note 1	Note 2

NOTES: 1. Primary: 120 μH (center-tapped)  
 $Q_U = 140$  at 455 kHz  
 Primary: Secondary turns ratio  $\approx 13$   
 2. Primary: 6.0 μH  
 Primary winding = 24 turns #36 AWG  
 (close-wound on 1/4" dia. form)  
 Core = Carbonyl E or J  
 Secondary winding = 1–1/2 turns #36 AWG, 1/4" dia.  
 (wound over center-tap)

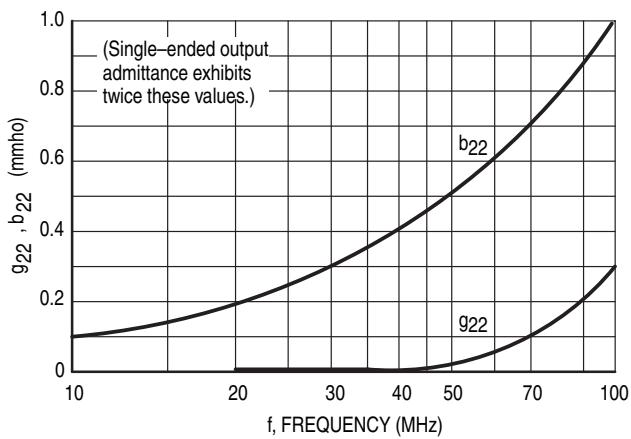
**Figure 8. Single-Ended Input Admittance**



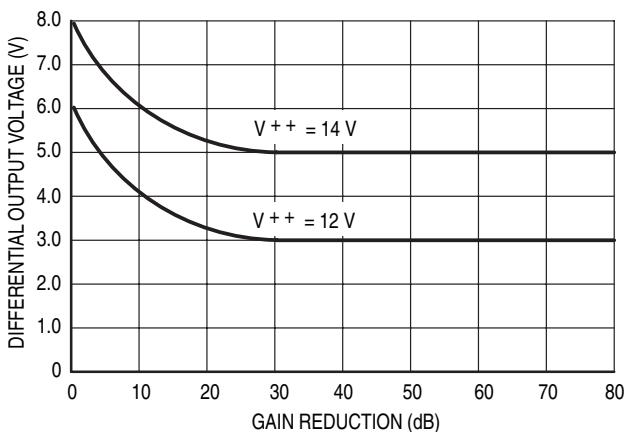
**Figure 9. Forward Transfer Admittance**



**Figure 10. Differential Output Admittance**

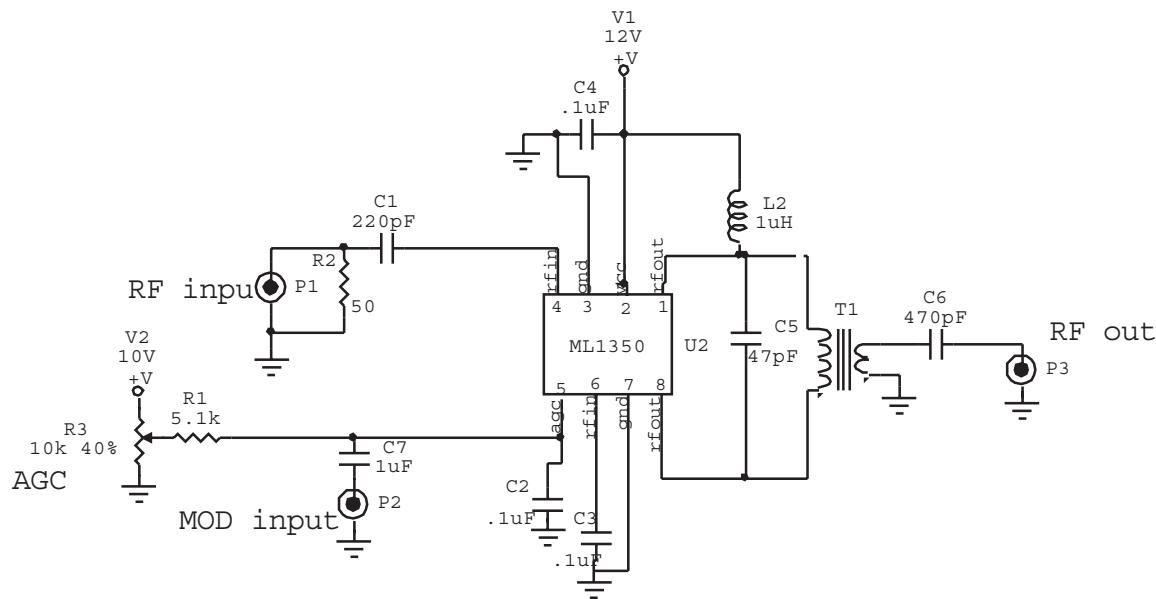


**Figure 11. Differential Output Voltage**



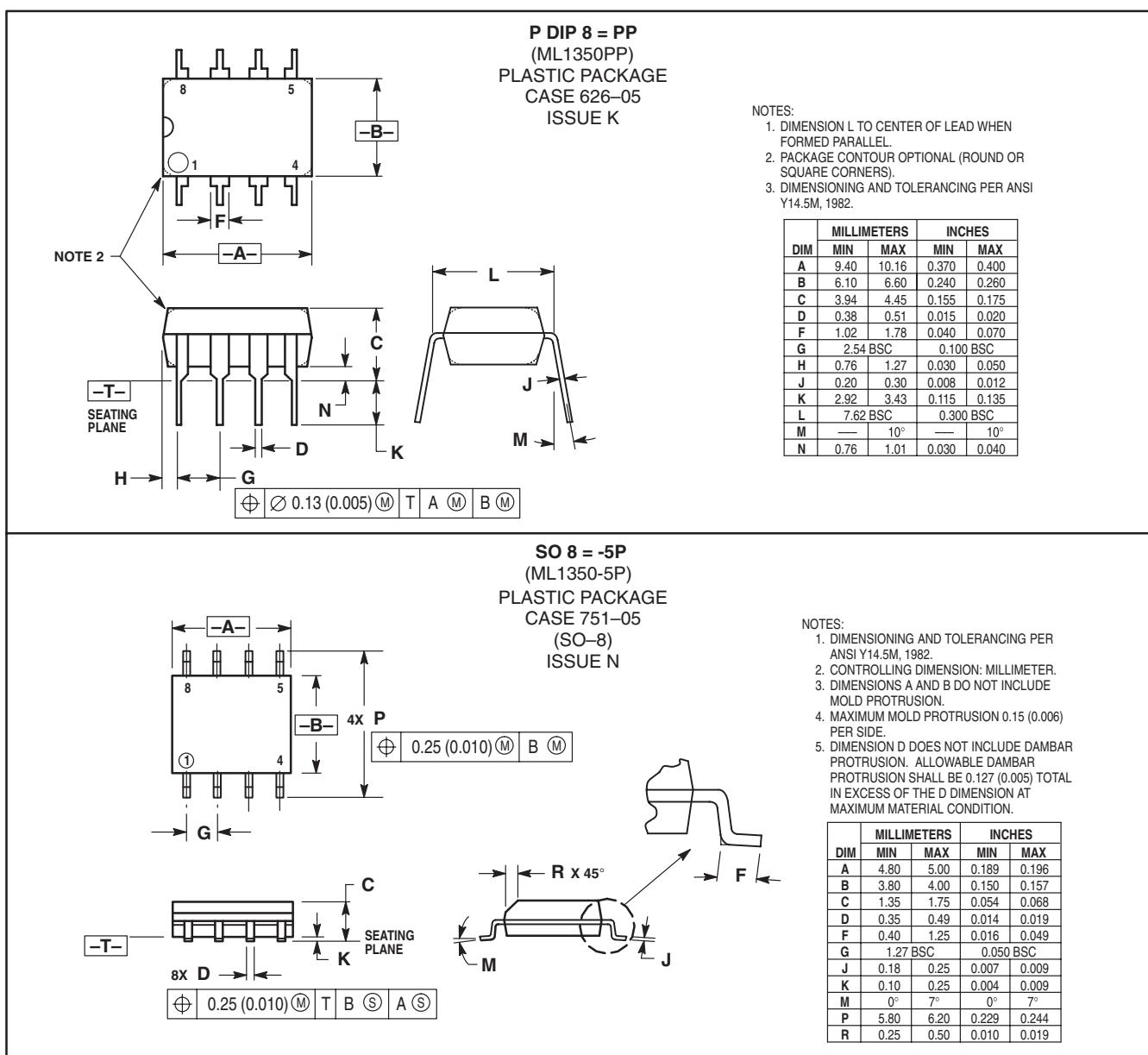
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**Figure 12. Typical application of a AM Modulator using ML1350**



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